

Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from, Europe, America and south Asia, supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



Contact us

Tel: +86-755-8981 8866 Fax: +86-755-8427 6832

Email & Skype: info@chipsmall.com Web: www.chipsmall.com

Address: A1208, Overseas Decoration Building, #122 Zhenhua RD., Futian, Shenzhen, China











N-Channel Power MOSFET

600V, 18A, 0.19Ω

FEATURES

- Super-Junction technology
- High performance, small R_{DS(ON)}*Q_g figure of merit (FOM)
- High ruggedness performance
- 100% UIS & Rg tested
- High commutation performance
- Pb-free plating
- Compliant to RoHS Directive 2011/65/EU and in accordance to WEEE 2002/96/EC
- Halogen-free according to IEC 61249-2-21

KEY PERFORMANCE PARAMETERS				
PARAMETER	PARAMETER VALUE UNIT			
V _{DS}	600	V		
R _{DS(on)} (max)	0.19	Ω		
Qg	31	nC		



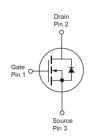




APPLICATIONS

- Power Supply
- AC/DC LED Lighting





Note: MSL 3 (Moisture Sensitivity Level) per J-STD-020

ABSOLUTE MAXIMUM RATINGS (T _A = 25°C unless otherwise noted)				
PARAMETER		SYMBOL	Limit	UNIT
Drain-Source Voltage		V_{DS}	600	V
Gate-Source Voltage		V_{GS}	±30	V
Continuous Drain Current (Note 1)	T _C = 25°C		18	Α
	$T_C = 100$ °C	- I _D	10.8	Α
Pulsed Drain Current (Note 2)		I _{DM}	54	Α
Total Power Dissipation @ T _C = 25°C		P _{DTOT}	150.6	W
Single Pulsed Avalanche Energy (Note 3)		E _{AS}	212.9	mJ
Single Pulsed Avalanche Current (Note 3)		I _{AS}	2.6	Α
Operating Junction and Storage Temperature Range		T_J,T_STG	- 55 to +150	°C

THERMAL PERFORMANCE				
PARAMETER	SYMBOL	Limit	UNIT	
Junction to Case Thermal Resistance	R _{eJC}	0.83	°C/W	
Junction to Ambient Thermal Resistance	R _{OJA}	62	°C/W	

Thermal Performance Note: $R_{\theta JA}$ is the sum of the junction-to-case and case-to-ambient thermal resistances. The case-thermal reference is defined at the solder mounting surface of the drain pins. $R_{\theta JA}$ is guaranteed by design while $R_{\theta CA}$ is determined by the user's board design. $R_{\theta JA}$ shown below for single device operation on FR-4 PCB with minimum recommended footprint in still air.

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PARAMETER	CONDITIONS	SYMBOL	MIN	TYP	MAX	UNIT
Static						
Drain-Source Breakdown Voltage	$V_{GS} = 0V, I_D = 250\mu A$	BV _{DSS}	600			V
Gate Threshold Voltage	$V_{DS} = V_{GS}, I_{D} = 250 \mu A$	$V_{GS(TH)}$	2.0	3.0	4.0	V
Gate Body Leakage	$V_{GS} = \pm 30V$, $V_{DS} = 0V$	I _{GSS}			±100	nA
Zero Gate Voltage Drain Current	$V_{DS} = 600V, V_{GS} = 0V$	I _{DSS}			1	μΑ
Drain-Source On-State Resistance (Note 4)	$V_{GS} = 10V, I_D = 6A$	R _{DS(on)}		0.17	0.19	Ω
Dynamic (Note 5)		1		•	L	
Total Gate Charge		Qg		31		nC
Gate-Source Charge	$V_{DS} = 380V, I_D = 18A,$ $V_{GS} = 10V$	Q _{gs}		8		
Gate-Drain Charge		Q_{gd}		12.6		
Input Capacitance	$V_{DS} = 100V, V_{GS} = 0V,$	C _{iss}		1273		_
Output Capacitance	f = 1.0MHz	C _{oss}		92		pF
Gate Resistance		R_g		3.1	6.2	Ω
Switching (Note 6)						
Turn-On Delay Time	$V_{DD} = 380V,$ $R_{GEN} = 25\Omega,$ $I_{D} = 18A, V_{GS} = 10V,$	t _{d(on)}		36		
Turn-On Rise Time		t _r		21		
Turn-Off Delay Time		t _{d(off)}		95		ns
Turn-Off Fall Time	$\frac{1}{10} = 10A, \text{ V}_{GS} = 10V,$	t _f		21		
Source-Drain Diode						
Forward On Voltage (Note 4)	I _S = 18A, V _{GS} = 0V	V_{SD}			1.4	٧
Reverse Recovery Time	V _B =100V, I _S = 18A	t _{rr}		359.4		ns
Reverse Recovery Charge	$dI_F/dt = 100A/\mu s$	Q _{rr}		4.54		μC

Notes:

- 1. Current limited by package.
- 2. Pulse width limited by the maximum junction temperature.
- 3. L=63mH, $I_{AS}=2.6A$, $V_{DD}=50V$, $R_{G}=25\Omega$, Starting $T_{J}=25^{\circ}C$
- 4. Pulse test: PW \leq 300 μ s, duty cycle \leq 2%.
- 5. For DESIGN AID ONLY, not subject to production testing.
- 6. Switching time is essentially independent of operating temperature.

ORDERING INFORMATION

PART NO.	PACKAGE	PACKING
TSM60NB190CM2 RNG	TO-263 (D ² PAK)	800pcs / 13" Reel

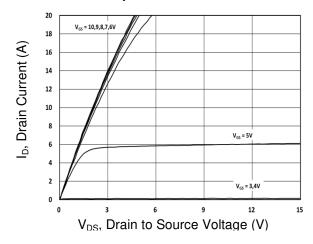


Taiwan Semiconductor

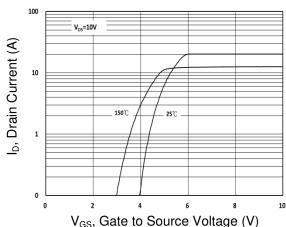
CHARACTERISTICS CURVES

(T_C = 25°C unless otherwise noted)

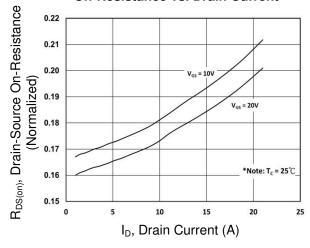
Output Characteristics



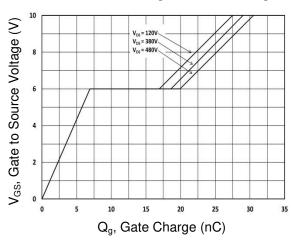
Transfer Characteristics



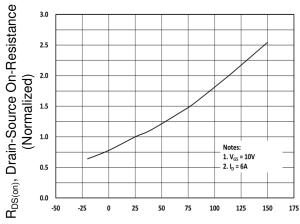
On-Resistance vs. Drain Current



Gate-Source Voltage vs. Gate Charge

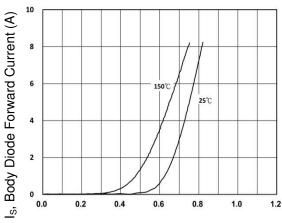


On-Resistance vs. Junction Temperature



T_J, Junction Temperature (°C)

Source-Drain Diode Forward Current vs. Voltage



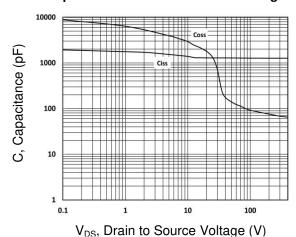
V_{SD}, Body Diode Forward Voltage (V)



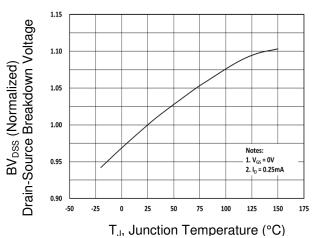
CHARACTERISTICS CURVES

 $(T_C = 25^{\circ}C \text{ unless otherwise noted})$

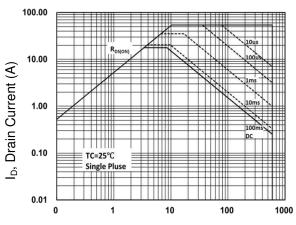
Capacitance vs. Drain-Source Voltage



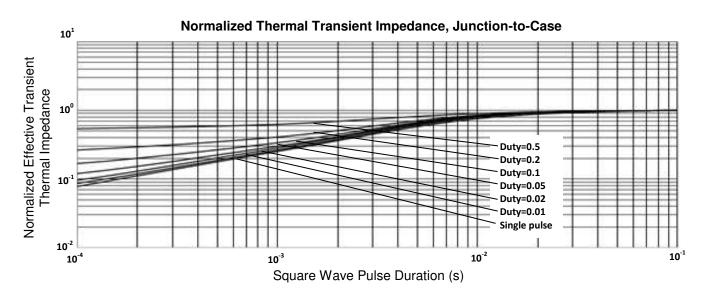
BV_{DSS} vs. Junction Temperature



Maximum Safe Operating Area



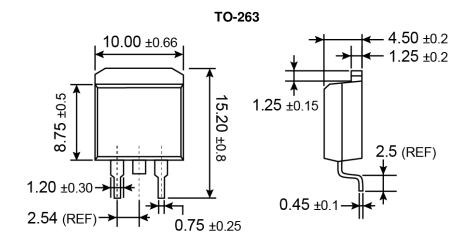
V_{DS}, Drain to Source Voltage (V)



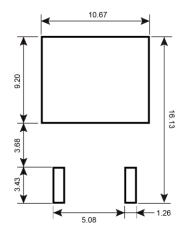
4



PACKAGE OUTLINE DIMENSIONS (Unit: Millimeters)



SUGGESTED PAD LAYOUT (Unit: Millimeters)



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MARKING DIAGRAM



G = Halogen Free

= Year Code

WW = Week Code (01~52)

= Factory Code





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